

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,971,432 B2
APPLICATION NO. : 10/639460
DATED : December 6, 2005
INVENTOR(S) : Kazutaka Yanagita et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page

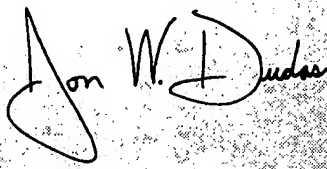
In Item (56), Title Page 2, Line 9, OTHER PUBLICATIONS, change:

“‘Oxidized Porous Silicon and It’s Application’, K. Nagano et al., *The Transactions of the Institute of Electronics and Communication Engineers*, The Institute of Electronics, Information and Communication” to

--“‘Oxidized Porous Silicon and It’s Application’, K. Nagano et al., *The Transactions of the Institute of Electronics and Communication Engineers*, The Institute of Electronics, Information and Communication”.--

Signed and Sealed this

Twentieth Day of November, 2007

A handwritten signature in black ink, reading "Jon W. Dudas", is written over a rectangular area with a light gray, textured background.

JON W. DUDAS

Director of the United States Patent and Trademark Office